

## MR27V1602D

1,048,576-Word x 16-Bit or 2,097,152-Word x 8-Bit One Time PROM

### DESCRIPTION

The MR27V1602D is a 16Mbit electrically Programmable Read-Only Memory whose configuration can be electrically switched between 1,048,576 word x 16bit and 2,097,152 word x 8bit. The MR27V1602D operates on a single +3V-3.3V power supply and is TTL compatible. Since the MR27V1602D operates asynchronously, external clocks are not required, making this device easy-to-use. The MR27V1602D is suitable as large-capacity fixed memory for microcomputers and data terminals. It is manufactured using a CMOS double silicon gate technology and is offered in 42-pin DIP, 44-pin SOP, 44-pin TSOP or 48-pin TSOP packages.

### FEATURES

- 1,048,576 word x 16bit / 2,097,152 word x 8bit electrically switchable configuration
- Single +3V-3.3V power supply
- Access time           100ns access time (Vcc=+3V)  
                              80ns access time (Vcc=+3.3V)
- Input / Output TTL compatible
- Three-state output
- Packages

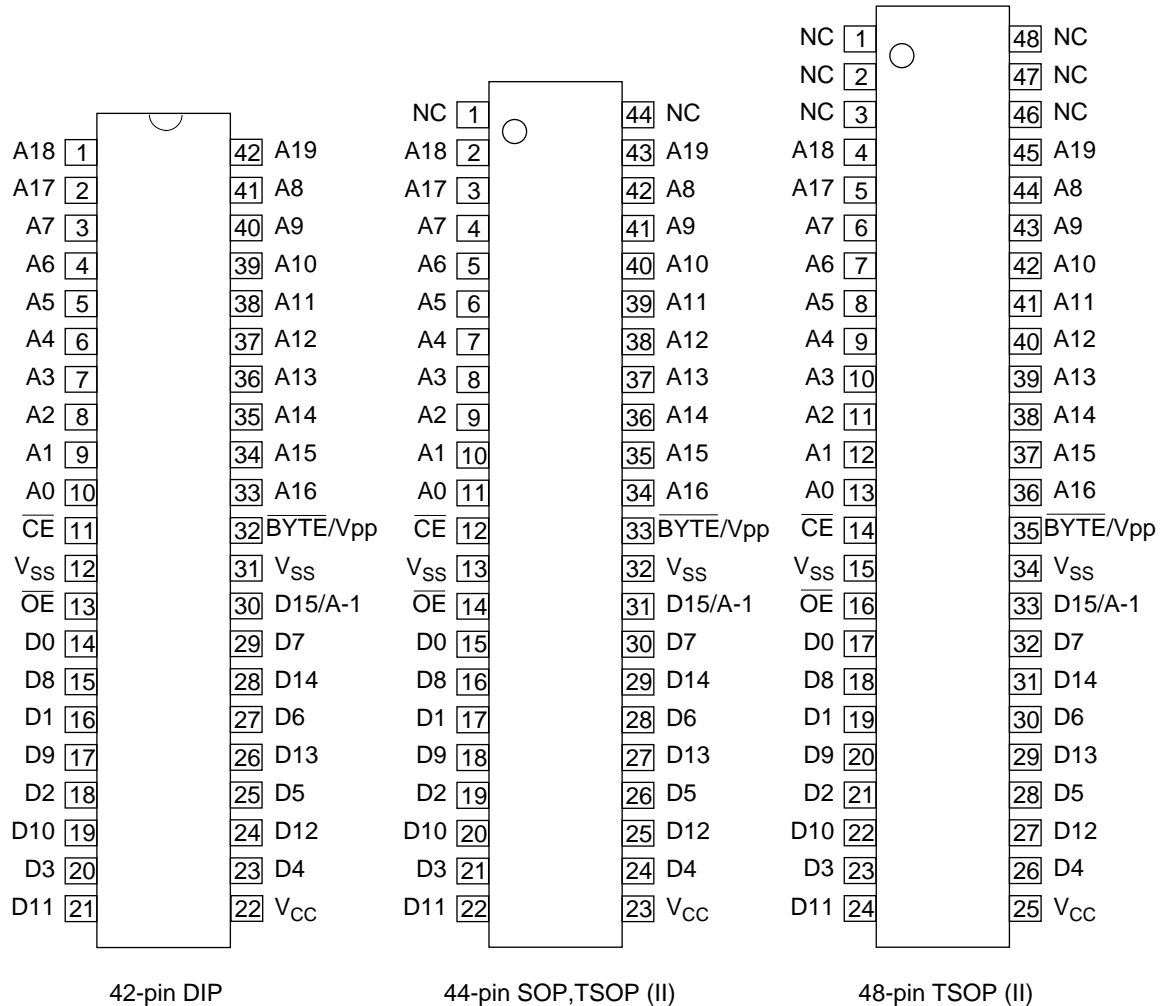
42-pin plastic DIP (DIP42-P-600-2.54)                   (Product name : MR27V1602DRA)

44-pin plastic SOP (SOP44-P-600-1.27-K)           (Product name : MR27V1602DMA)

44-pin plastic TSOP (TSOP II 44-P-400-0.80-K) (Product name : MR27V1602DTP)

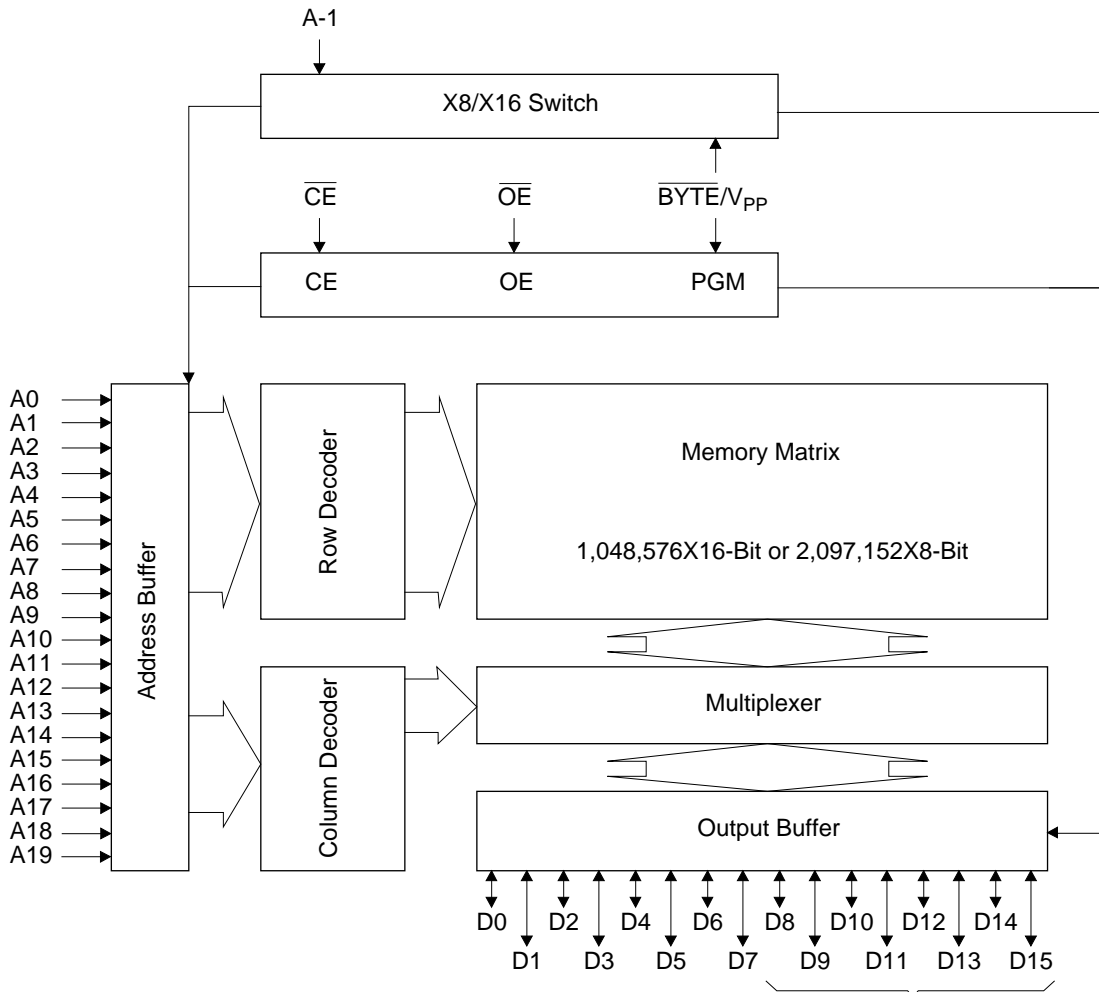
48-pin plastic TSOP (TSOP II 48-P-550-0.80-K) (Product name : MR27V1602DTA)

## PIN CONFIGURATION (TOP VIEW)



| PIN NAMES       | FUNCTIONS                                  |
|-----------------|--|
| D15/A-1         | Data output / Address input                |
| A0-A19          | Address input                              |
| D0-D14          | Data output                                |
| $\overline{CE}$ | Chip enable                                |
| $\overline{OE}$ | Output enable                              |
| $V_{CC}$        | Power supply voltage                       |
| $V_{SS}$        | GND  |
| BYTE/ $V_{PP}$  | Mode switch / Program power supply voltage |
| NC              | Non connection                             |

## BLOCK DIAGRAM



In 8-bit output mode, these pins are three-stated and pin D15 functions as the A-1 address pin.

## FUNCTION TABLE

| MODE            | $\overline{\text{CE}}$ | $\overline{\text{OE}}$ | $\overline{\text{BYTE}}/V_{\text{PP}}$ | $V_{\text{CC}}$    | D0 - D7          | D8 - D14 | D15/A-1 |
|-----------------|------------------------|------------------------|--|--------------------|------------------|----------|---------|
| READ (16-Bit)   | L                      | L                      | H                                      | 3.0V<br>to<br>3.3V | $D_{\text{OUT}}$ |          |         |
| READ (8-Bit)    | L                      | L                      | L                                      |                    | $D_{\text{OUT}}$ | Hi-Z     | L/H     |
| OUTPUT DISABLE  | L                      | H                      | H                                      |                    | Hi-Z             |          | *       |
|                 |                        |                        | L                                      |                    | Hi-Z             |          | *       |
| STAND-BY        | H                      | *                      | H                                      | Hi-Z               |                  | *        |         |
|                 |                        |                        | L                                      | Hi-Z               |                  | *        |         |
| PROGRAM         | L                      | H                      | 9.75V                                  | $D_{\text{IN}}$    |                  |          |         |
| PROGRAM INHIBIT | H                      | H                      |  | Hi-Z               |                  |          |         |
| PROGRAM VERIFY  | H                      | L                      |  | $D_{\text{OUT}}$   |                  |          |         |

\*: Don't Care

**ABSOLUTE MAXIMUM RATINGS**

| Parameter                        | Symbol    | Condition            | Value                  | Unit |
|----------------------------------|-----------|----------------------|------------------------|------|
| Operating temperature under bias | $T_{opr}$ | -                    | 0 to 70                | °C   |
| Storage temperature              | $T_{stg}$ |                      | -55 to 125             | °C   |
| Input voltage                    | $V_I$     | relative to $V_{SS}$ | -0.5 to $V_{CC} + 0.5$ | V    |
| Output voltage                   | $V_O$     |                      | -0.5 to $V_{CC} + 0.5$ | V    |
| Power supply voltage             | $V_{CC}$  |                      | -0.5 to 5              | V    |
| Program power supply voltage     | $V_{PP}$  |                      | -0.5 to 11.5           | V    |
| Power dissipation per package    | $P_D$     | -                    | 1.0                    | W    |

**RECOMMENDED OPERATING CONDITIONS**

(Ta=0 to 70°C)

| Parameter                     | Symbol   | Condition          | Min.   | Typ. | Max.           | Unit |
|-------------------------------|----------|--------------------|--------|------|----------------|------|
| $V_{CC}$ power supply voltage | $V_{CC}$ | $V_{CC}=2.7V-3.6V$ | 2.7    | -    | 3.6            | V    |
| $V_{PP}$ power supply voltage | $V_{PP}$ |                    | -0.5   | -    | $V_{CC}+0.5$   | V    |
| Input "H" level               | $V_{IH}$ |                    | 2.2    | -    | $V_{CC}+0.5^*$ | V    |
| Input "L" level               | $V_{IL}$ |                    | -0.5** | -    | 0.6            | V    |

Voltage is relative to  $V_{SS}$ \* :  $V_{CC}+1.5V$  (Max.) when pulse width of overshoot is less than 10nS.

\*\* : -1.5V (Min.) when pulse width of undershoot is less than 10nS.

**ELECTRICAL CHARACTERISTICS (Read operation)****DC Characteristics 1**(V<sub>CC</sub>=3V±0.3V, T<sub>a</sub>=0 to 70°C)

| Parameter                                      | Symbol            | Condition   | Min.   | Typ. | Max.                  | Unit |
|--|-------------------|---|--------|------|-----------------------|------|
| Input leakage current                          | I <sub>LI</sub>   | V <sub>I</sub> =0 to V <sub>CC</sub>                  | -      | -    | 10                    | μA   |
| Output leakage current                         | I <sub>LO</sub>   | V <sub>O</sub> =0 to V <sub>CC</sub>                  | -      | -    | 10                    | μA   |
| V <sub>CC</sub> power supply current (Standby) | I <sub>CCSC</sub> | $\overline{CE}=V_{CC}$                                | -      | -    | 50                    | μA   |
|  | I <sub>CCST</sub> | $\overline{CE}=V_{IH}$                                | -      | -    | 1                     | mA   |
| V <sub>CC</sub> power supply current (Read)    | I <sub>CCA</sub>  | $\overline{CE}=V_{IL}, \overline{OE}=V_{IH}$ tc=100ns | -      | -    | 35                    | mA   |
| V <sub>PP</sub> power supply current           | I <sub>PP</sub>   | V <sub>PP</sub> =V <sub>CC</sub>                      | -      | -    | 10                    | μA   |
| Input "H" level                                | V <sub>IH</sub>   | -   | 2.2    | -    | V <sub>CC</sub> +0.5* | V    |
| Input "L" level                                | V <sub>IL</sub>   | -   | -0.5** | -    | 0.6                   | V    |
| Output "H" level                               | V <sub>OH</sub>   | I <sub>OH</sub> =-400uA                               | 2.4    | -    | -                     | V    |
| Output "L" level                               | V <sub>OL</sub>   | I <sub>OL</sub> =2.1mA                                | -      | -    | 0.4                   | V    |

Voltage is relative to V<sub>SS</sub>\* : V<sub>CC</sub>+1.5V (Max.) when pulse width of overshoot is less than 10nS.

\*\* : -1.5V (Min.) when pulse width of undershoot is less than 10nS.

**DC Characteristics 2**(V<sub>CC</sub>=3.3V±0.3V, T<sub>a</sub>=0 to 70°C)

| Parameter                                      | Symbol            | Condition  | Min.   | Typ. | Max.                  | Unit |
|--|-------------------|--|--------|------|-----------------------|------|
| Input leakage current                          | I <sub>LI</sub>   | V <sub>I</sub> =0 to V <sub>CC</sub>                 | -      | -    | 10                    | μA   |
| Output leakage current                         | I <sub>LO</sub>   | V <sub>O</sub> =0 to V <sub>CC</sub>                 | -      | -    | 10                    | μA   |
| V <sub>CC</sub> power supply current (Standby) | I <sub>CCSC</sub> | $\overline{CE}=V_{CC}$                               | -      | -    | 50                    | μA   |
|  | I <sub>CCST</sub> | $\overline{CE}=V_{IH}$                               | -      | -    | 1                     | mA   |
| V <sub>CC</sub> power supply current (Read)    | I <sub>CCA</sub>  | $\overline{CE}=V_{IL}, \overline{OE}=V_{IH}$ tc=80ns | -      | -    | 40                    | mA   |
| V <sub>PP</sub> power supply current           | I <sub>PP</sub>   | V <sub>PP</sub> =V <sub>CC</sub>                     | -      | -    | 10                    | μA   |
| Input "H" level                                | V <sub>IH</sub>   | -  | 2.2    | -    | V <sub>CC</sub> +0.5* | V    |
| Input "L" level                                | V <sub>IL</sub>   | -  | -0.5** | -    | 0.6                   | V    |
| Output "H" level                               | V <sub>OH</sub>   | I <sub>OH</sub> =-400uA                              | 2.4    | -    | -                     | V    |
| Output "L" level                               | V <sub>OL</sub>   | I <sub>OL</sub> =2.1mA                               | -      | -    | 0.4                   | V    |

Voltage is relative to V<sub>SS</sub>\* : V<sub>CC</sub>+1.5V (Max.) when pulse width of overshoot is less than 10nS.

\*\* : -1.5V (Min.) when pulse width of undershoot is less than 10nS.

**AC Characteristics 1** $(V_{CC}=3V\pm 0.3V, T_a=0 \text{ to } 70^\circ\text{C})$ 

| Parameter                   | Symbol    | Condition                            | Min. | Max. | Unit |
|-----------------------------|-----------|--------------------------------------|------|------|------|
| Address cycle time          | $T_C$     | -                                    | 100  | -    | ns   |
| Address access time         | $T_{ACC}$ | $\overline{CE}=\overline{OE}=V_{IL}$ | -    | 100  | ns   |
| $\overline{CE}$ access time | $T_{CE}$  | $\overline{OE}=V_{IL}$               | -    | 100  | ns   |
| $\overline{OE}$ access time | $T_{OE}$  | $\overline{CE}=V_{IL}$               | -    | 50   | ns   |
| Output disable time         | $T_{CHZ}$ | $\overline{OE}=V_{IL}$               | 0    | 30   | ns   |
|                             | $T_{OHZ}$ | $\overline{CE}=V_{IL}$               | 0    | 25   | ns   |
| Output hold time            | $T_{OH}$  | $\overline{CE}=\overline{OE}=V_{IL}$ | 0    | -    | ns   |

## Measurement conditions

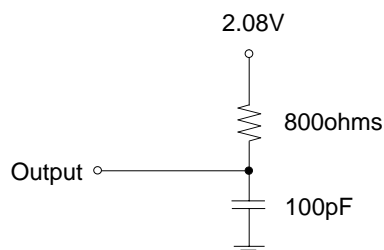
|                               |       |           |
|-------------------------------|-------|-----------|
| Input signal level            | ----- | 0V/3V     |
| Input timing reference level  | ----- | 0.8V/2.0V |
| Output load                   | ----- | 100pF     |
| Output timing reference level | ----- | 0.8V/2.0V |

**AC Characteristics 2** $(V_{CC}=3.3V\pm 0.3V, T_a=0 \text{ to } 70^\circ\text{C})$ 

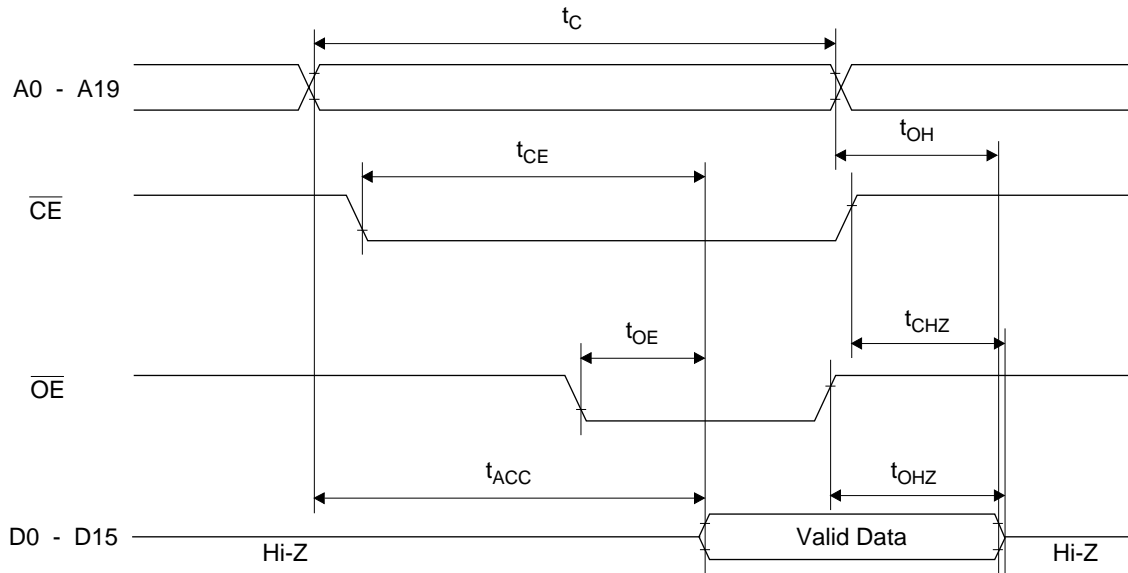
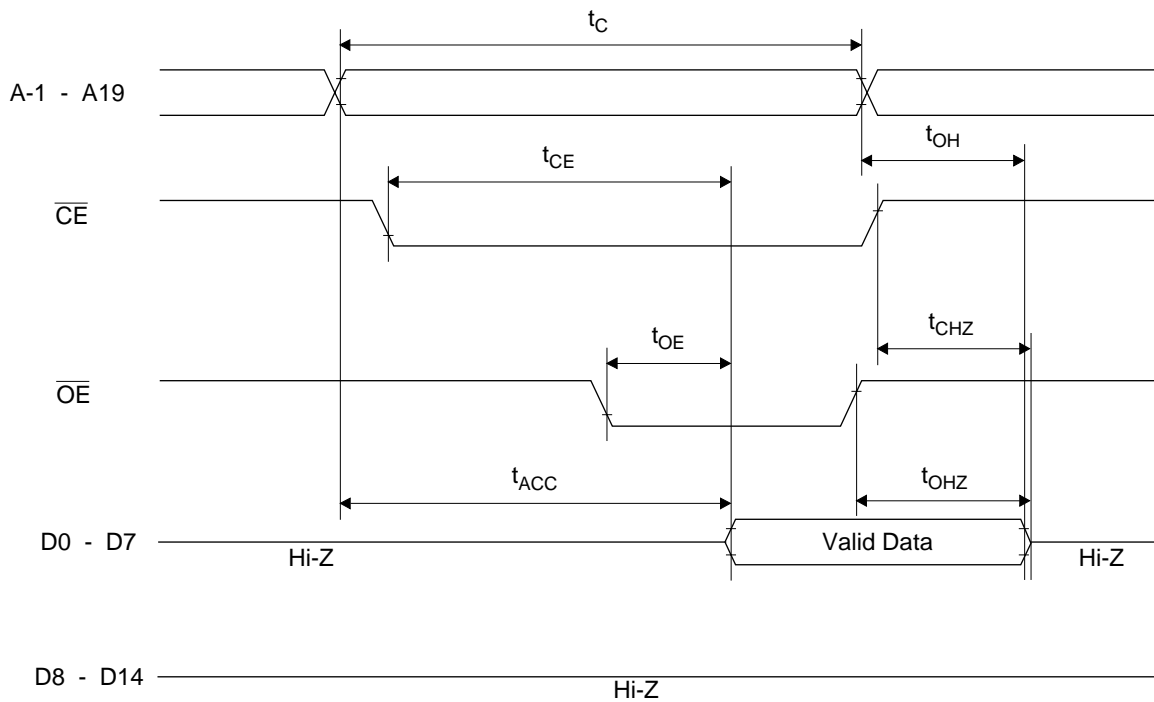
| Parameter                   | Symbol    | Condition                            | Min. | Max. | Unit |
|-----------------------------|-----------|--------------------------------------|------|------|------|
| Address cycle time          | $T_C$     | -                                    | 80   | -    | ns   |
| Address access time         | $T_{ACC}$ | $\overline{CE}=\overline{OE}=V_{IL}$ | -    | 80   | ns   |
| $\overline{CE}$ access time | $T_{CE}$  | $\overline{OE}=V_{IL}$               | -    | 80   | ns   |
| $\overline{OE}$ access time | $T_{OE}$  | $\overline{CE}=V_{IL}$               | -    | 40   | ns   |
| Output disable time         | $T_{CHZ}$ | $\overline{OE}=V_{IL}$               | 0    | 30   | ns   |
|                             | $T_{OHZ}$ | $\overline{CE}=V_{IL}$               | 0    | 25   | ns   |
| Output hold time            | $T_{OH}$  | $\overline{CE}=\overline{OE}=V_{IL}$ | 0    | -    | ns   |

## Measurement conditions

|                               |       |           |
|-------------------------------|-------|-----------|
| Input signal level            | ----- | 0V/3V     |
| Input timing reference level  | ----- | 0.8V/2.0V |
| Output load                   | ----- | 100pF     |
| Output timing reference level | ----- | 0.8V/2.0V |



## TIMING CHART (READ CYCLE)

16-Bit Read Mode ( $\overline{\text{BYTE}}=V_{\text{IH}}$ )8-Bit Read Mode ( $\overline{\text{BYTE}}=V_{\text{IL}}$ )

**ELECTRICAL CHARACTERISTICS (Programming operation)****DC Characteristics**

(Ta=25°C±5°C)

| Parameter                                      | Symbol           | Condition                             | Min. | Typ. | Max.                 | Unit |
|--|------------------|---------------------------------------|------|------|----------------------|------|
| Input leakage current                          | I <sub>LI</sub>  | V <sub>I</sub> =V <sub>CC</sub> +0.5V | -    | -    | 10                   | μA   |
| V <sub>PP</sub> power supply current (Program) | I <sub>PP2</sub> | $\overline{CE}=V_{IL}$                | -    | -    | 50                   | mA   |
| V <sub>CC</sub> power supply current           | I <sub>CC</sub>  | -                                     | -    | -    | 50                   | mA   |
| Input "H" level                                | V <sub>IH</sub>  | -                                     | 3.0  | -    | V <sub>CC</sub> +0.5 | V    |
| Input "L" level                                | V <sub>IL</sub>  | -                                     | -0.5 | -    | 0.8                  | V    |
| Output "H" level                               | V <sub>OH</sub>  | I <sub>OH</sub> =-400μA               | 2.4  | -    | -                    | V    |
| Output "L" level                               | V <sub>OL</sub>  | I <sub>OL</sub> =2.1mA                | -    | -    | 0.45                 | V    |
| Program voltage                                | V <sub>PP</sub>  | -                                     | 9.5  | 9.75 | 10.0                 | V    |
| V <sub>CC</sub> power supply voltage           | V <sub>CC</sub>  | -                                     | 3.9  | 4.0  | 4.1                  | V    |

Voltage is relative to V<sub>SS</sub>**AC Characteristics**(V<sub>CC</sub>=4.0V±0.1V, V<sub>pp</sub>=9.75V±0.25V, Ta=25°C±5°C)

| Parameter                               | Symbol           | Condition | Min. | Typ. | Max. | Unit |
|---|------------------|-----------|------|------|------|------|
| Address set-up time                     | T <sub>AS</sub>  | -         | 100  | -    | -    | ns   |
| $\overline{OE}$ set-up time             | T <sub>OES</sub> | -         | 2    | -    | -    | μs   |
| Data set-up time                        | T <sub>DS</sub>  | -         | 100  | -    | -    | ns   |
| Address hold time                       | T <sub>AH</sub>  | -         | 2    | -    | -    | μs   |
| Data hold time                          | T <sub>DH</sub>  | -         | 100  | -    | -    | ns   |
| Output float delay from $\overline{OE}$ | T <sub>OHZ</sub> | -         | 0    | -    | 100  | ns   |
| V <sub>PP</sub> voltage set-up time     | T <sub>VS</sub>  | -         | 2    | -    | -    | μs   |
| Program pulse width                     | T <sub>PW</sub>  | -         | 9    | 10   | 11   | μs   |
| Data valid from $\overline{OE}$         | T <sub>OE</sub>  | -         | -    | -    | 100  | ns   |
| Address hold from $\overline{OE}$ high  | T <sub>AHO</sub> | -         | 0    | -    | -    | ns   |

**Pin Check Function**

Pin Check Function is to check contact between each device-pin and each socket-lead with EPROM programmer.

Setting up address as the following condition call the preprogrammed codes on device outputs.

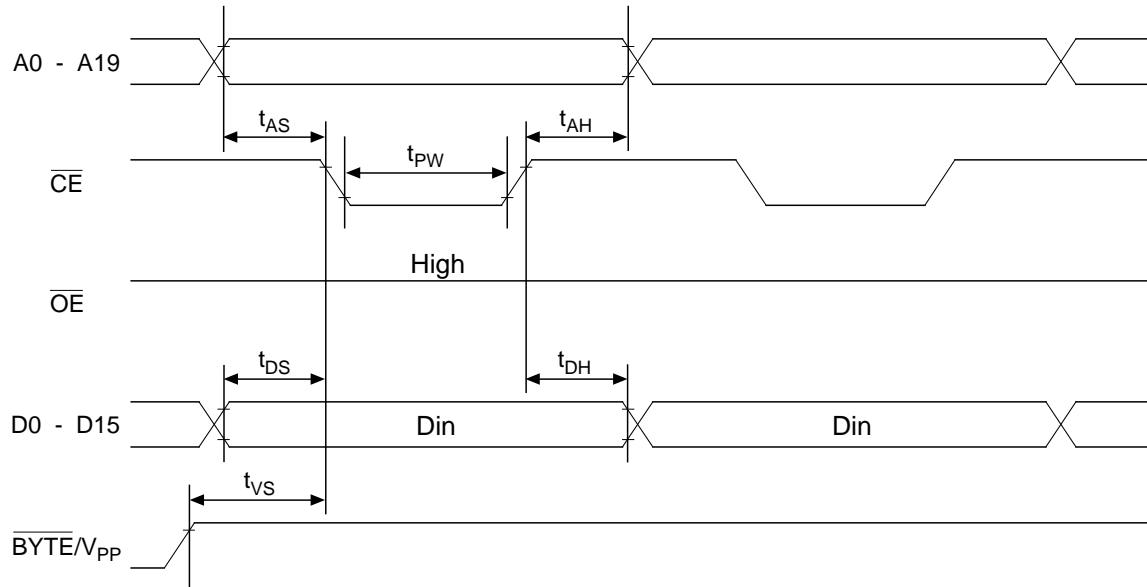
(V<sub>CC</sub>=3.3V±0.3V,  $\overline{CE}=\overline{OE}=V_{IL}$ ,  $\overline{BYTE}/V_{pp}=V_{IH}$ , Ta=25°C±5°C)

| A0               | A1 | A2 | A3 | A4 | A5 | A6 | A7 | A8 | A9  | A10 | A11 | A12 | A13 | A14 | A15 | A16 | A17 | A18 | A19 | DATA |
|------------------|----|----|----|----|----|----|----|----|-----|-----|-----|-----|-----|-----|-----|-----|-----|-----|-----|------|
| 0                | 1  | 0  | 1  | 0  | 1  | 0  | 1  | 0  | VH* | 0   | 1   | 0   | 1   | 0   | 1   | 0   | 0   | 1   | 1   | FF00 |
| 1                | 0  | 1  | 0  | 1  | 0  | 1  | 0  | 1  | VH* | 1   | 0   | 1   | 0   | 1   | 0   | 1   | 1   | 0   | 0   | 00FF |
| Other conditions |    |    |    |    |    |    |    |    |     |     |     |     |     |     |     |     |     |     |     | FFFF |

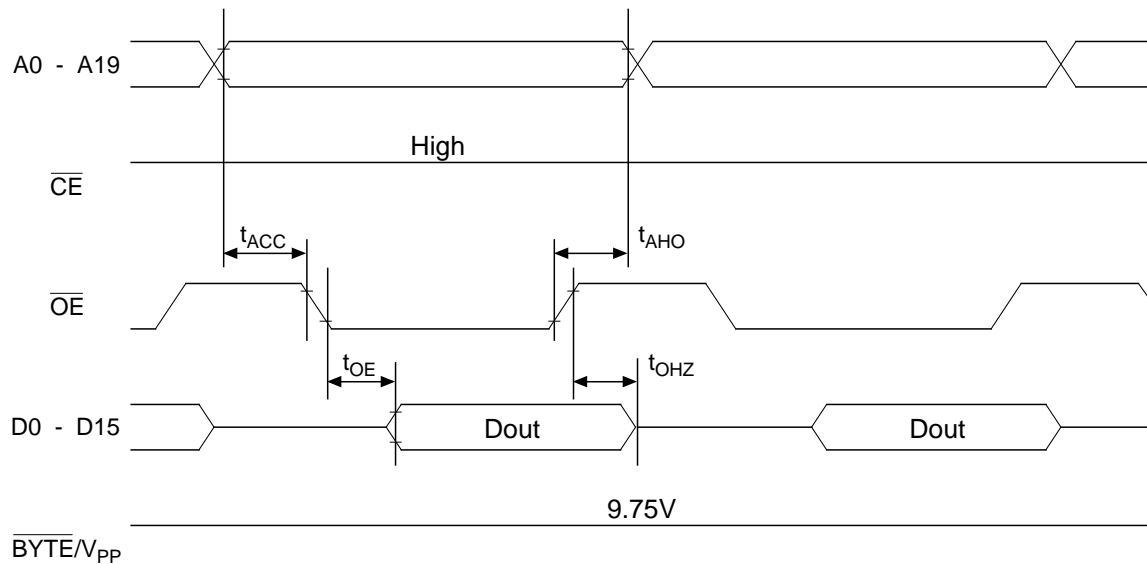
\*: VH=8V±0.25V



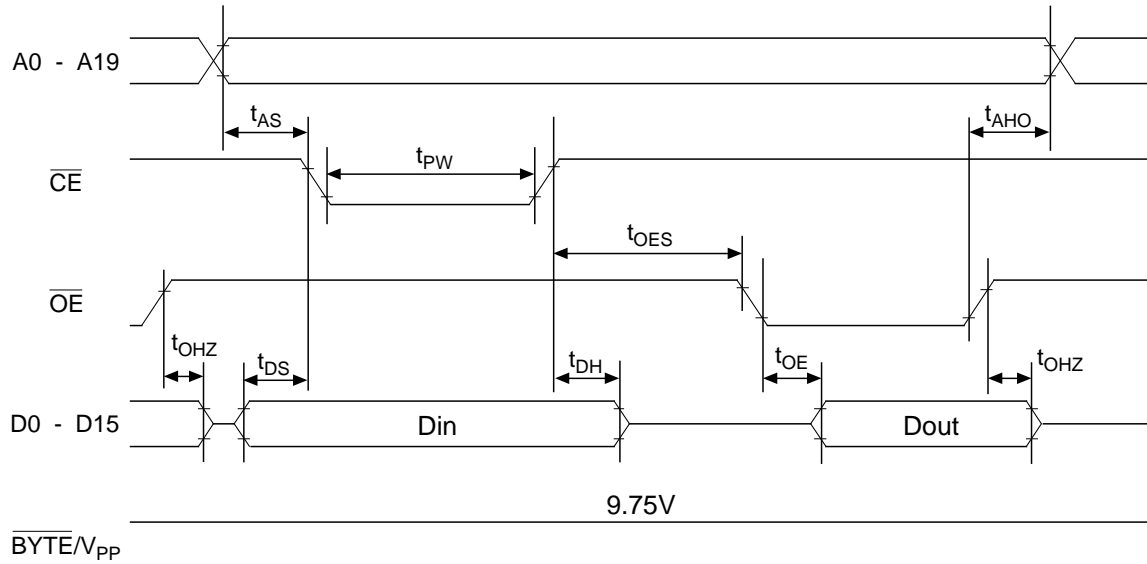
### Consecutive Programming Waveforms



### Consecutive Program Verify Waveforms



### Program and Program Verify Cycle Waveforms



### PIN Capacitance

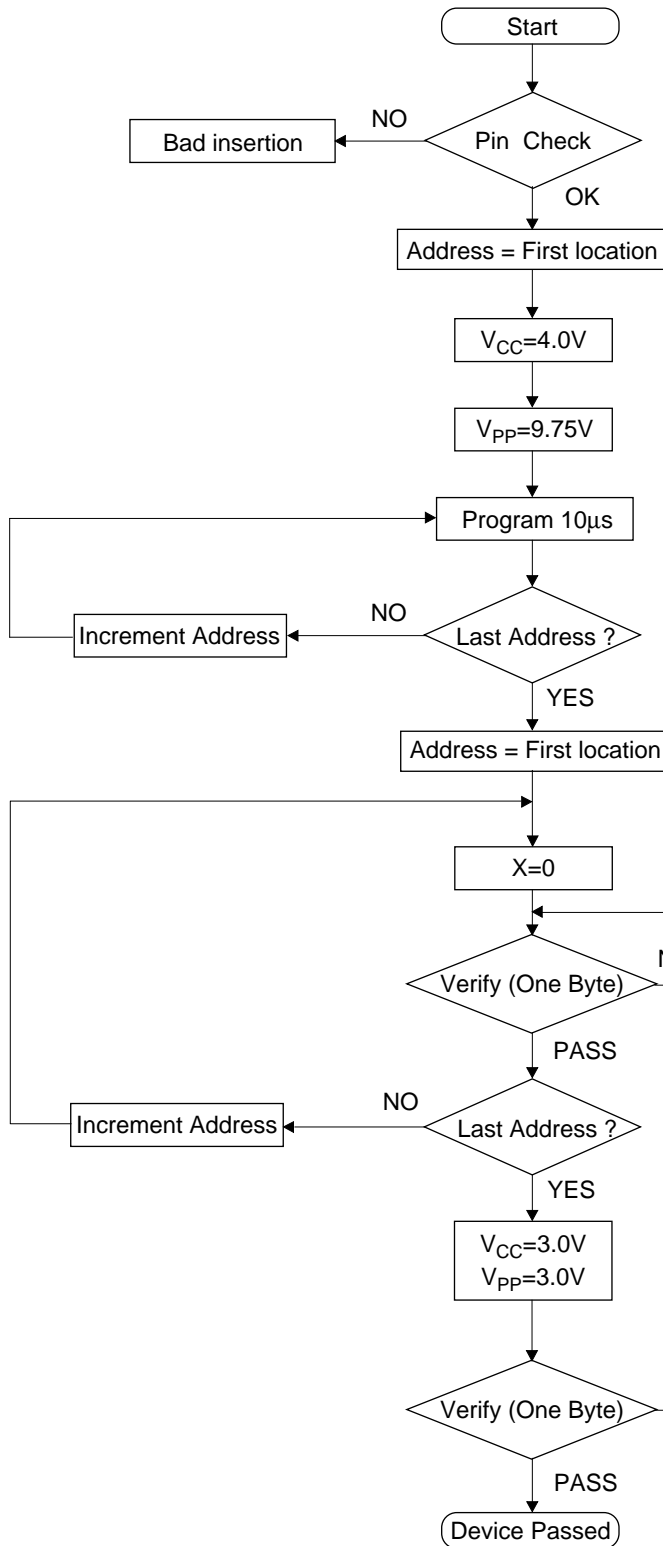
( $V_{CC}=3.3V, T_a=25^\circ C, f=1MHz$ )

| Parameter                | Symbol    | Condition | Min. | Typ. | Max.    | Unit |
|--------------------------|-----------|-----------|------|------|---------|------|
| Input                    | $C_{IN1}$ | $V_I=0V$  | -    | -    | 8 (10)  | pF   |
| $\overline{BYTE}/V_{PP}$ | $C_{IN2}$ |           | -    | -    | 120     |      |
| Output                   | $C_{OUT}$ | $V_O=0V$  | -    | -    | 10 (12) |      |

( ) : DIP only

## Programming / Verify Flow Chart

## Programming



## Verify

